FORM HDP-1449 (Based on F

PATENT AND TRADEMARK OFFICE INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)

Sheet 1 of 1

UI 10 Rec a P	CIPIU OJ OLI ZUU4
ATTORNEY DOCKET No.	SERIAL NO. NA 56
91000-000014/US	NEW APPLICATION
APPLICANT	
Björn STOLTZ, et al.	,
FILING DATE	GROUP
September 3, 2004	Unknown

U.S. PATENT DOCUMENTS						
Ref. Desig.	Examiner's Initials	Document Number	Date	Name	Class/ Subclass	(If appropriate) Filing Date
	SA	5,538,918	07/23/1996	HAASE et al.		
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Ref.	Examiner's Initials	Document			Class/	Translatio	
Desig.		Number	Date	Country	Subclass	Yes	. No
	· SA	WO 01/13479 A1	02/22/2001	WIPO		Yes	-
*	SA	WO 99/39413	08/05/1999	WIPO		Yes	
	SA	DE 38 10 767 A1	10/12/1989	GERMAN			No.

Ref. Desig.	Examiner's Initials	
	SA	N. BOUADMA et al., "1.3-µm GaInAsP/InP Buried-Ridge-Structure Laser and its Monolithic Integration with Photodetector Using Reactive Ion Beam Etching", Journal of Lightwave Technology, Vol. 12, May 15, 1999, Pgs. 742-748
	SA	P. OJala et al., "DFB LASER MONOLITHICALLY INTEGRATED WITH AN ABSORPTION MODULATOR WITH LOW RESIDUAL REFLECTANCE AND SMALL CHIRP", Electronics Letters, May 13, 1993, Vol. 29 No. 10, Pgs. 859-860
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Examiner:	/Shamim Ahmed/ (11/08/2006)	Date Considered:	11/08/2006	